

Spezifikationen	
Teilenummer	FDMS9411_F085
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 40V 8PQFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2568 pcs Stock
VGS (th) (Max) @ Id	4V @ 250μA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	8-PQFN (5x6), Power56
Serie	Automotive, AEC-Q101, PowerTrench®
Rds On (Max) @ Id, Vgs	7.8 mOhm @ 30A, 10V
Verlustleistung (max)	68.2W (Tj)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 20V
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Tc)

sein:

ON Semiconductor

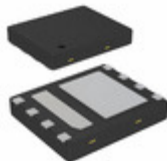
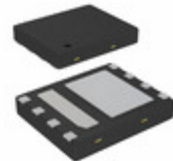
Fairchild

FDMS9410_F085

Fairchild/ON Semiconductor
MOSFET N-CH 40V 50A 8PQFN

FDMS9620S

AMI Semiconductor / ON
Semiconductor
MOSFET 2N-CH 30V 7.5A/10A
PWR56

 FDMS9600S Fairchild/ON Semiconductor MOSFET 2N-CH 30V 12A/16A POWER56	 FDMS9411L_F085 Fairchild/ON Semiconductor MOSFET NCH 40V 30A POWER56	 FDMS9411 FAIRCHILD FDMS9411 FAIRCHILD
 FDMS9600S MOS ON ON QFN8	 FDMS9411-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 8PQFN	 FDMS9600S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 12A/16A POWER56

Mehr

Fairchild/ON Semiconductor	FDM9411_F085 Datenblatt	FDM9411_F085-Datenblätter	FDM9411_F085 PDF	Fairchild/ON Semiconductor FDM9411_F085
FDM9411_F085 Electronic	FDM9411_F085-Komponenten	FDM9411_F085-Verteiler	FDM9411_F085-Bild	FDM9411_F085-Teil
FDM9411_F085 Preis	FDM9411_F085 Hersteller	FDM9411_F085 Bild	FDM9411_F085 Aktie	FDM9411_F085 Inventar
FDM9411_F085 Neu	FDM9411_F085 Original	FDM9411_F085 garantiert	FDM9411_F085 RFQ	FDM9411_F085 Online bestellen